

220CNQ030

**Green Products** 

Technical Data Data Sheet N1196, Rev. B

# 220CNQ030 SCHOTTKY RECTIFIER

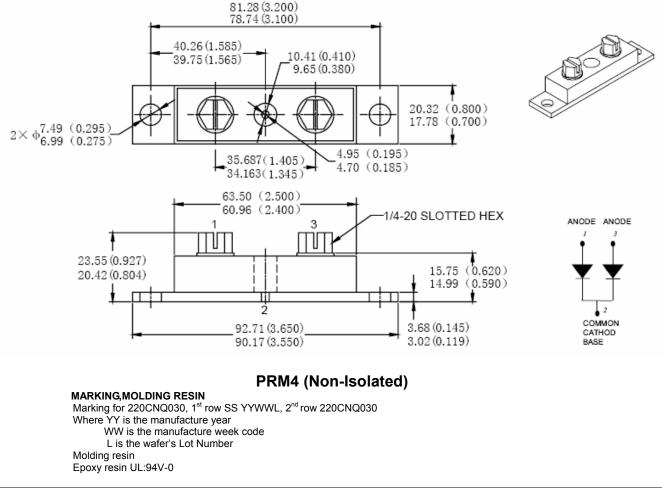
### **Applications:**

- High current switching power supply Free-Wheeling diodes Reverse battery protection
- Converters 
  Welding

#### Features:

- 150°C T<sub>J</sub> operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Mechanical Dimensions: In mm/ Inches



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# SANGDEST MICROELECTRONICS

# 220CNQ030

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#### **Technical Data** Data Sheet N1196, Rev. B Maximum Ratings:

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Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	30		V
Max. Average Forward	1	50% duty cycle $@T_c = 100^{\circ}C$ ,	110	per leg	A
	I <sub>F(AV)</sub>	rectangular wave form	220	per device	
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	2880		А
Non-Repetitive Avalanche Energy(peg leg)	E <sub>AS</sub>	T <sub>J</sub> =25℃,I <sub>AS</sub> =22A,L=0.41mH	99		mJ
Repetitive Avalanche Current(peg leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ sec Frequency limited by T <sub>J</sub> max. V <sub>A</sub> =1.5× V <sub>R</sub> typical		22	A

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 110A, Pulse, T <sub>J</sub> = 25 °C	0.48	V
(per leg) *		@ 220A, Pulse, T <sub>J</sub> = 25 °C	0.57	
	V <sub>F2</sub>	@ 110A, Pulse, T <sub>J</sub> = 125 °C	0.40	V
		@ 220A, Pulse, T <sub>J</sub> = 125 °C	0.52	
Max. Reverse Current at DC	L.	$@V_R = rated V_R$	10	mA
condition	I <sub>R1</sub>	T <sub>J</sub> = 25 °C	10	
Max. Reverse Current	I <sub>R2</sub>	$@V_R = rated V_R$	560	mA
	IR2	T <sub>J</sub> = 125 °C	500	
Max. Junction Capacitance	CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	7400	pF
		f <sub>SIG</sub> = 1MHz	7400	
Typical Series Inductance	Ls	Measured lead to lead 5 mm	7.0	nH
(per leg)	LS	from package body	7.0	
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs
Insulation Voltage	V <sub>RMS</sub>	-	1000	V

\* Pulse Width < 300µs, Duty Cycle <2%

### **Thermal-Mechanical Specifications:**

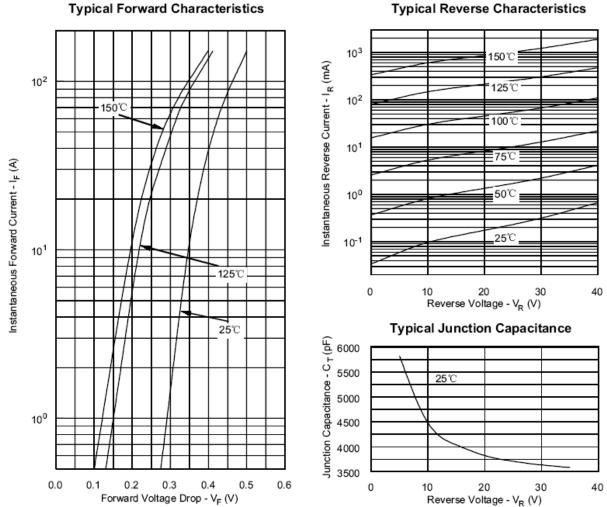
Characteristics	Symbol	Condition	Specifi	Units		
Max. Junction Temperature	TJ	-	-55 to	°C		
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to	°C		
Maximum Thermal Resistance Junction to Case (per leg)	R <sub>θJC</sub>	DC operation	0.50		°C/W	
Maximum Thermal Resistance Junction to Case (per device)	R <sub>θJC</sub>	DC operation	0.25		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ ext{ heta}cs}$	Mounting surface, smooth and greased	0.10		°C/W	
Mounting Torque	Тм	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm	
Approximate Weight	wt	-	79	g		
Case Style	PRM4 (Non-Isolated)					

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**Typical Reverse Characteristics** 

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